

General Description

This product family offers state of the art performance. It is designed for high frequency applications where high efficiency and high reliability are required.

Features

- Low conduction loss due to low VF
- Extremely low switching loss by tiny Qc
- Highly rugged due to better surge current
- · Industrial standard quality and reliability

Applications

- UPS
- Power Inverter
- High performance SMPS
- · Power factor correction

Ordering Part Number	Package	Marking
HC3D50170H	TO-247-2L	HC3D50170H







Absolute Maximum Ratings (Tj = 25° C)

_	Parameter	Symbol	Value	Unit
Reverse voltage (repetitive peak)		V_{RM}	1700	V
Reverse voltage (DC)		V_R	1700	V
Continuous forward current (T _c =145°C)		I _F	50 ^{*1}	А
Surge non- repetitive forward current	PW=10ms sinusoidal, T _j =25°C		150	А
	PW=10ms sinusoidal, T _j =150°C	/=10ms sinusoidal, T _j =150°C		
	PW=10μs square, T _j =25°C		630	А
i ² t value	1≦PW≦10ms, T _j =25°C	$\int i^2 dt$	120	A ² s
	1≦PW≦10ms, T _j =150°C	J i⁻dt	60	A ² s
Junction temperature		T _j	175	°C
Range of storage temperature		T_{stg}	-55 to +175	°C

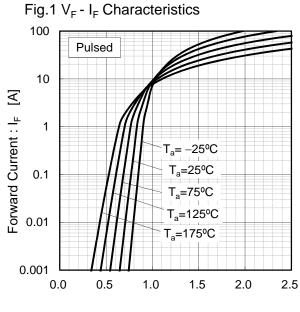
^{*1} Limited by T_j *2 Assumes $Z_{th(j-a)}$ of 0.16 °C/W or less. (Pulse Width = 8.3ms)



Electrical characteristics (Tj = 25°C)

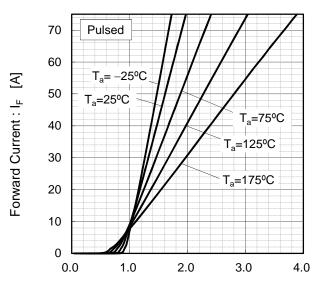
Parameter	Symbol	Conditions	Values			Unit	
Faranielei	Symbol	Conditions	Min.	Тур.	Max.	Offic	
DC blocking voltage	V_{DC}	I _R =0.3mA	1700	-	-	V	
		I _F =50A,T _j =25°C	-	1.65	1.95	V	
Forward voltage	V_{F}	I _F =50A,T _j =150°C	-	2.5	-	V	
		I _F =50A,T _j =175°C	-	2.8	-	V	
	I _R	V _R =1700V,T _j =25°C	-	5	300	μΑ	
Reverse current		V _R =1700V,T _j =150°C	-	110	-	μΑ	
		V _R =1700V,T _j =175°C	-	250	-	μΑ	
Total conscitones	С	V _R =1V,f=1MHz	-	3100	-	pF	
Total capacitance		V _R =1700V,f=1MHz	-	170	-	pF	
Total capacitive charge	Q_{C}	V _R =800V,di/dt=500A/μs	-	158	-	nC	
Switching time	t _C	V _R =800V,di/dt=500A/μs -		39	-	ns	

Electrical characteristic curves



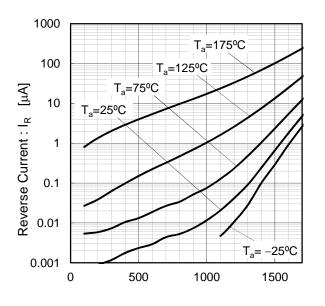
Forward Voltage : V_F [V]

Fig.2 V_F - I_F Characteristics



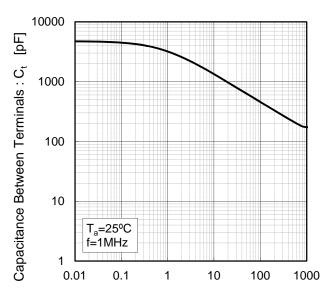
Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics



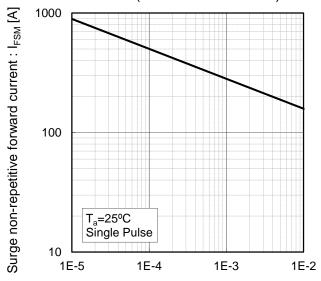
Reverse Voltage: V_R [V]

Fig.4 V_R-C_t Characteristics



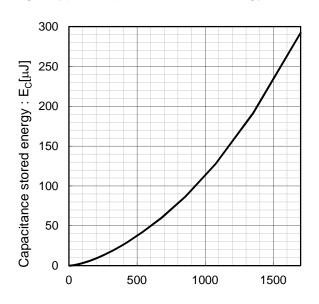
Reverse Voltage: V_R [V]

Fig.5 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)*



 $Pulse\ Width: PW\ [s] $* Assumes $Z_{th(j-a)}$ of 0.38 °C/W or less. (Pulse\ Width = 8.3ms)$

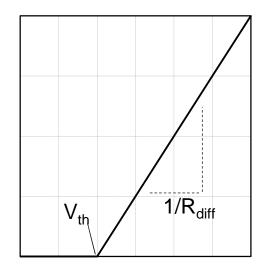
Fig.6 Typical capacitance store energy



Reverse Voltage : V_R [V]

Forward Current : I_F

Fig.7 Equivalent forward current curve



Forward Voltage : V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$\begin{aligned} &V_{th}\left(\:T_{j}\:\right) = a_{0} + a_{1}\:T_{j} \\ &R_{diff}\left(\:T_{j}\:\right) = b_{0} + b_{1}\:T_{j} + b_{2}\:T_{j}^{2} \end{aligned}$$

Symbol	Typical Value	Unit	
a_0	9.21E-01	V	
a ₁	- 1.52E-03	V/°C	
b_0	1.20E-02	Ω	
b ₁	8.13E-05	Ω/°C	
b ₂	5.64E-07	Ω/°C ²	

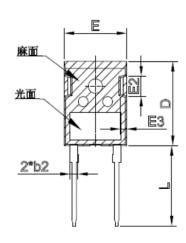
 $\rm T_{j}$ in °C; -55 °C < $\rm T_{j}$ < °C ; $\rm I_{F}$ < 100A

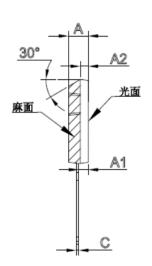


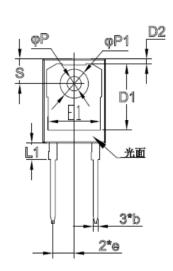
Package Dimensions

Package TO-247-2L

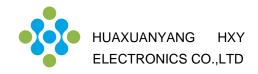
Unitmm







	Min	Nom	Max		Min	Nom	Max
Α	4.70	5.00	5.20	E1	13.06	13.26	13.56
A1	2.30		2.50	E2	4.90	5.00	5.10
A2	1.90	2.00	2.10	E3	1.50	1.60	1.70
b	1.10	1.20	1.30	8	5.34	5.44	5.54
b2		2.00		L	19.80	20.00	20.32
				L1		4.17	4.50
С	0.5	0.6	0.7	Р	3.50	3.60	3.70
D	20.8	20.95	21.1	P1	7.00	7.19	7.40
D1		16.55		S	6.04	6.15	6.3
D2	0.95	1.17	1.35				
E	15.48	15.88	16.28				



Attention

- Any and all HUA XUAN YANG ELECTRONICS products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your HUA XUAN YANG ELECTRONICS representative nearest you before using any HUA XUAN YANG ELECTRONICS products described or contained herein in such applications.
- HUA XUAN YANG ELECTRONICS assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all HUA XUAN YANG ELECTRONICS products described or contained herein.
- Specifications of any and all HUA XUAN YANG ELECTRONICS products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- HUA XUAN YANG ELECTRONICS CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all HUA XUAN YANG ELECTRONICS products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of HUA XUAN YANG ELECTRONICS CO.,LTD.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. HUA XUAN YANG ELECTRONICS believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc.

 When designing equipment, refer to the "Delivery Specification" for the HUA XUAN YANG ELECTRONICS product that you intend to use.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by HXY MOS manufacturer:

Other Similar products are found below:

MA4E2039 MMBD301M3T5G RB160M-50TR D83C RKS100KG#P1 BAS 3010S-02LRH E6327 BAT 54-02LRH E6327

NRVBAF360T3G NSR05F40QNXT5G NTE555 SB10-04A3-BT SBM30-03-TR-E SBS811-S-TL-E SBS818-TL-E SS3003CH-TL-E

STPS30S45CW GA01SHT18 CRS10I30A(TE85L,QM MBRB30H30CT-1G BAT 15-04R E6152 IDL08G65C5 JANTX1N5712-1 SB007
03C-TB-E SB10015M-TL-E NRVBB20100CTT4G NRVBM120LT1G NTSB30U100CT-1G STPS40SM100CG-TR CRG04(T5L,TEMQ)

ACDBA240-HF CDBQC0530L-HF STPS40SM120CTN NRVBM120ET1G STPS2545CGY-TR B160BQ-13-F SDM05U20CSP-7 BAS 70
07 E6433 HSM560Je3/TR13 HSM190Je3/TR13 B330AF-13 ACDBUC0230-HF MBR10200CTF-G1 CDLL5712 DMF2822-000 VS
50WQ04FNTRL-M3 1N5817-G B350AF-13 MF300A06F2 SEMIX302KD16S 5082-2835